

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of:

Takashi KOBAYASHI et al.

Appln. No.:

Filed: Herewith

For: NONVOLATILE SEMICONDUCTOR MEMORY DEVICE AND
MANUFACTURING METHOD THEREOF

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PRELIMINARY AMENDMENT

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

Prior to examination, please amend the above-
identified patent application as indicated below.

Amendments to the specification begin on page 2 of
this paper.

Amendments to the Claims are reflected in the listing
of claims which begins on page 4 of this paper.

Remarks begin on page 17 of this paper.